

Quantum Cascade Photodetector (QCD)

P16309-01



Ultrafast mid-infrared quantum cascade photodetector

This is an ultrafast mid-infrared photodetector with a response bandwidth of 20 GHz. It operates bias free with no cooling required, so no external power supplies are needed. It explores the application such the high frequency and high time resolved measurement like a Heterodyne detection in mid-infrared region.

Features

- **High-speed response: DC to 20 GHz**
- **Peak sensitivity wavelength: 4.65 μm typ.**
- **Photosensitivity: 1 mA/W typ.**
- **Non-cooled, non-bias operation**

Applications

- **Heterodyne detection**
- **High frequency / high time resolved measurement**

Structure

Parameter	Specification	Unit
Connector type	SMA	-
Cooling	Non-cooled	-
Lens	Focusing lens ^{*1}	-
Aperture	$\phi 4.5$	mm
Polarizing direction	Marked in the body ^{*2}	-

*1: Incident light have to be colimated.

*2: Refer to P4 Dimensional outline.

Absolute maximum ratings

Parameter	Symbol	Value	Unit
Incident light level ^{*3}	Pmax	1	W/cm ²
Operating temperature ^{*4}	Topr	-10 to +50	°C
Storage tempera ^{*4}	Tstg	-10 to +50	°C

*3: Ta=25 °C

*4: No dew condensation

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

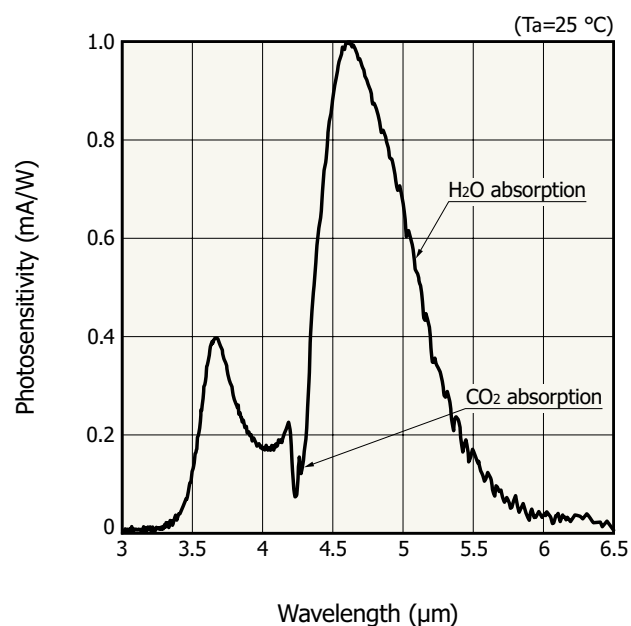
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Non-bias operation is required.

Electrical and optical characteristics (Ta=25 °C)

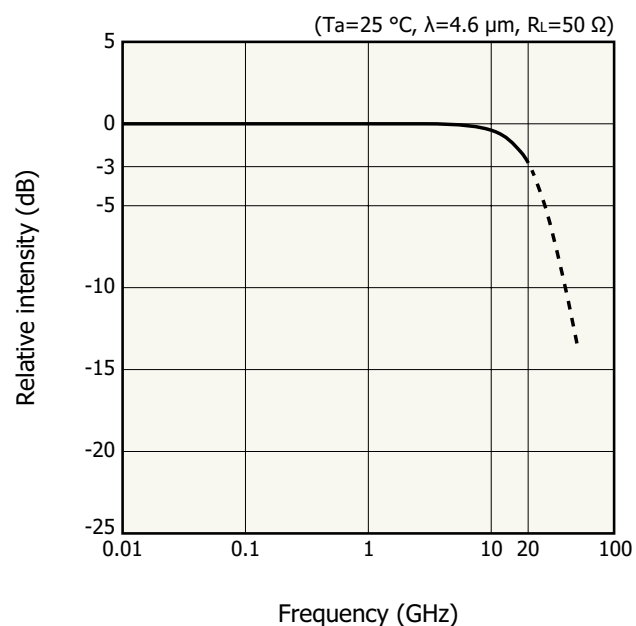
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Peak sensitivity wavelength	λ_p		4.6	4.65	4.7	μm
Photosensitivity	S	$\lambda=\lambda_p, f_0=800 \text{ Hz}, \Delta f=1 \text{ Hz}$	0.5	1	-	mA/W
Detectivity	D^*	$\lambda=\lambda_p, f_0=800 \text{ Hz}, \Delta f=1 \text{ Hz}$	8.0×10^8	1.5×10^9	-	$\text{cm}^2\text{Hz}^{1/2}/\text{W}$
Noise equivalent power	NEP	$\lambda=\lambda_p, f_0=800 \text{ Hz}$	-	3.0×10^{-10}	1.0×10^{-9}	$\text{W/Hz}^{1/2}$
Cutoff frequency	f_c	-3 dB, $R_L=50 \Omega$	18	20	-	GHz
Terminal capacitance	C_t	$f=1 \text{ MHz}$	-	1.1	1.5	pF
Shunt resistance	R_{sh}	$V_R=10 \text{ mV}$	70	90	110	$\text{k}\Omega$

Spectral response (typical example)



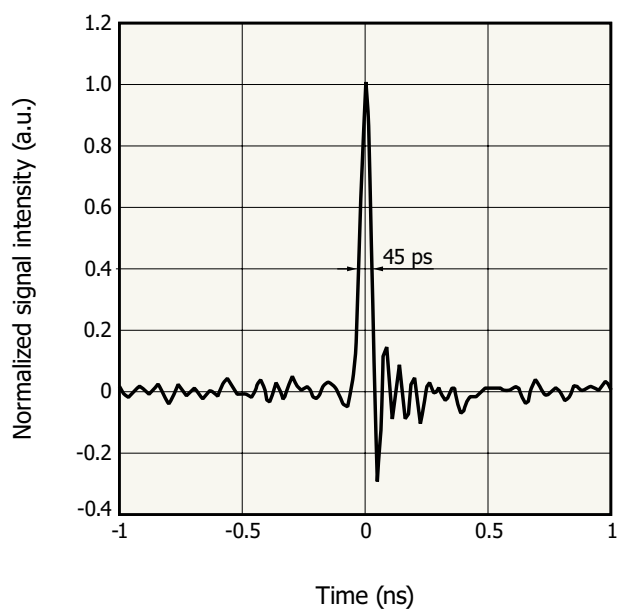
KIRDB0744EA

Frequency characteristics (typical example)



KIRDB0745EA

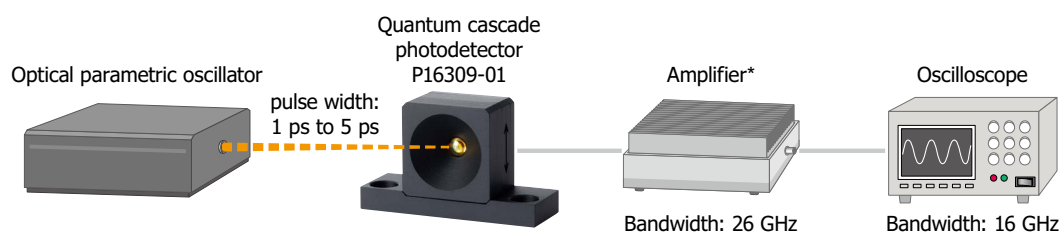
■ Ultrashort pulse waveform measurement (measurement example)



<Data provided>
Ideguchi group, The University of Tokyo

KIRD80746EA

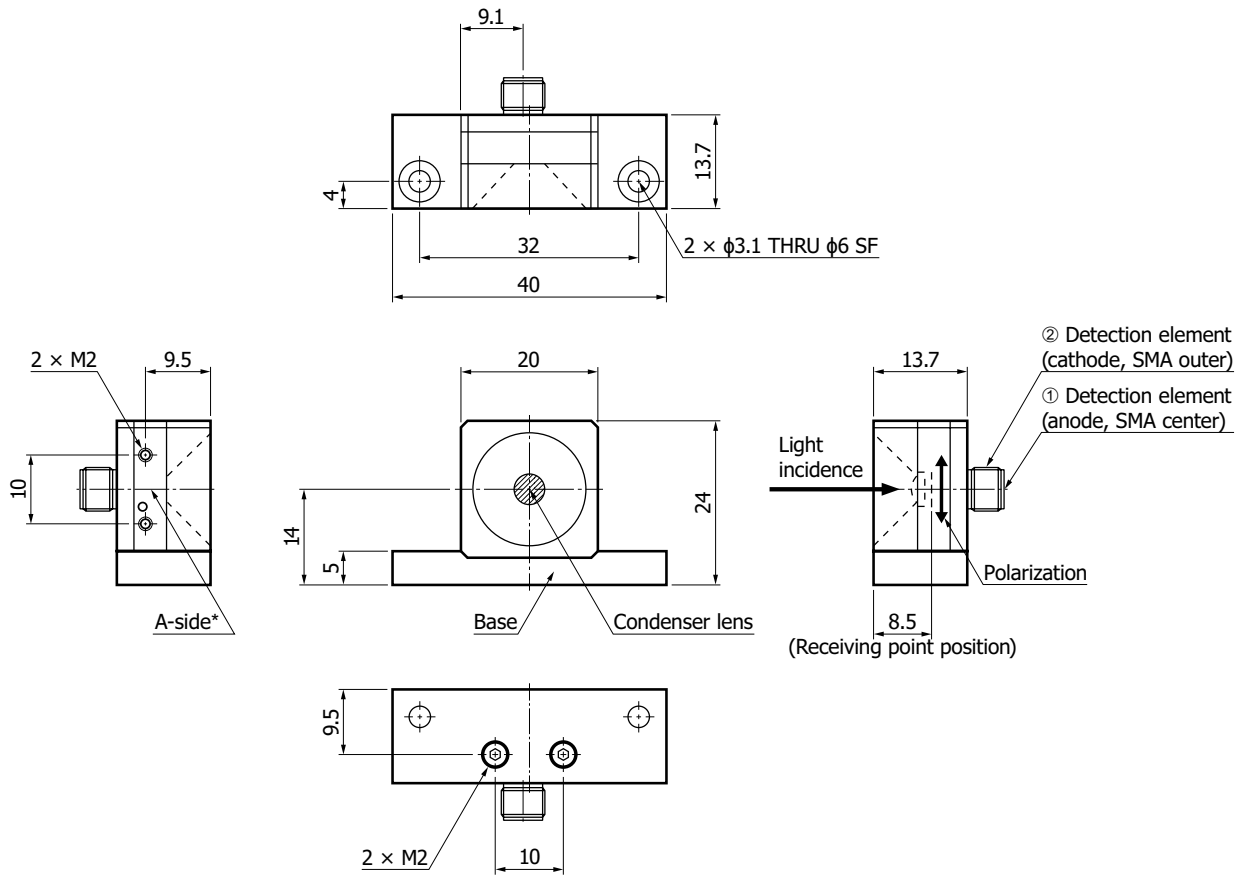
■ Measurement configuration



* Example of equipment: Keysight technologies, 83006A

KIRDC0150EA

Dimensional outline (unit: mm)



* A-side can be fixed on the base as the bottom aspect.
Tolerance unless otherwise noted: ± 0.3
Both ① and ② are electrically insulated from the package.

KIRDA0296EA

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

- Disclaimer
- Safety consideration / Opto-semiconductor products
- Precautions / Compound opto-semiconductors (photosensors, light emitters)

The content of this document is current as of April 2025.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

HAMAMATSU

www.hamamatsu.com

Optical Semiconductor Sales, HAMAMATSU PHOTONICS K.K.

1126-1 Ichino-cho, Chuo-ku, Hamamatsu City, Shizuoka Pref., 435-8558 Japan, Telephone: (81)53-434-3311, Fax: (81)53-434-5184

U.S.A.: HAMAMATSU CORPORATION: 360 Foothill Road, Bridgewater, NJ 08807, U.S.A., Telephone: (1)908 231 0960, Fax: (1)908 231 1218

Germany: HAMAMATSU PHOTONICS DEUTSCHLAND GMBH: Arzbergerstr. 10, 82211 Herrsching am Ammersee, Germany, Telephone: (49)8152 375 0, Fax: (49)8152 265 8 E mail: info@hamamatsu.de

France: HAMAMATSU PHOTONICS FRANCE S.A.R.L.: 19 Rue du Saule Trappu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: (33)1 69 53 71 00, Fax: (33)1 69 53 71 10 E mail: infos@hamamatsu.fr

United Kingdom: HAMAMATSU PHOTONICS UK LIMITED: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire, AL7 1BW, UK, Telephone: (44)1707 294888, Fax: (44)1707 325777 E mail: info@hamamatsu.co.uk

North Europe: HAMAMATSU PHOTONICS NORDEN AB: Torshamnsgatan 35, 16440 Kista, Sweden, Telephone: (46)8 509 031 00, Fax: (46)8 509 031 01 E mail: info@hamamatsu.se

Italy: HAMAMATSU PHOTONICS ITALIA S.R.L.: Strada della Moia, 1 int. 6 20044 Arese (Milano), Italy, Telephone: (39)02 93 58 17 33, Fax: (39)02 93 58 17 41 E mail: info@hamamatsu.it

China: HAMAMATSU PHOTONICS (CHINA) CO., LTD.: 1201, Tower B, Jiaming Center, 27 Dongsanhuan Bellu, Chaoyang District, 100020 Beijing, P.R. China, Telephone: (86)10 6586 6006, Fax: (86)10 6586 2866 E mail: hpc@hamamatsu.com.cn

Taiwan: HAMAMATSU PHOTONICS TAIWAN CO., LTD.: 13F 1, No.101, Section 2, Gongdao 5th Road, East Dist., Hsinchu City, 300046, Taiwan(R.O.C) Telephone: (886)3 659 0080, Fax: (886)3 659 0081 E mail: info@hamamatsu.com.tw

Korea: HAMAMATSU PHOTONICS KOREA CO., LTD.: A 912, 167, Songpa daero, Seoul, 05855, Korea, Telephone: (82)2 2054 8202, Fax: (82)2 2054 8207 E mail: sales@hpk.co.kr